

ISC Silicon NPN Power Transistor

BDX11

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 140V (Min)
- · High Current Capability
- · Wide area of safe operation
- · 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

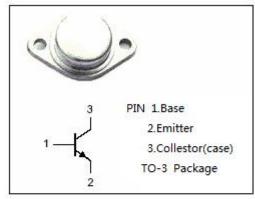


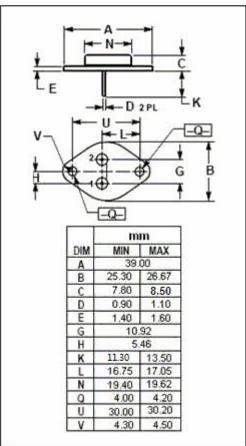
APPLICATIONS

• Designed for general-purpose power amplifier and switching applications.



SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	160	V
V _{CEO}	Collector-Emitter Voltage	140	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	10	А
Ісм	Collector Current-Peak	15	А
Pc	Collector Power Dissipation 11		W
TJ	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range -55~150		${\mathbb C}$







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =5A; I _B = 0.5A			1.0	V
V _{CE} (sat)-2	Collector-Emitter Saturation Voltage	I _C = 10A; I _B = 1A			2.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C =5A; I _B = 0.5A			1.5	V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	140			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	6			V
h _{FE-1}	DC Current Gain	I _C =1A; V _{CE} = 4V	60		200	
h _{FE-2}	DC Current Gain	I _C =3A; V _{CE} = 4V	20		70	
h _{FE-3}	DC Current Gain	I _C =10A; V _{CE} = 4V	10			
I _{CBO}	Collector Cutoff Current	V _{CB} =160V ; I _E = 0			100	uA
I _{EBO}	Emitter Cutoff Current	V _{EB} =6V; I _C = 0			100	uA
f⊤	Current-Gain—Bandwidth Product	I _C = 0.1A; V _{CE} = 10V; f _{test} = 1.0MHz	4			MHz

NOTICE:

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